

$$V_{D} = V_{DD} - I_{C}, R_{D}$$
 and  $I_{C_{1}} = \beta I_{B_{1}} = \beta \frac{V_{me_{2}} - V_{B}}{R_{me_{2}}}$ 

design for 
$$V_0 = \frac{V_{00} + V_B}{2} = V_{00} - R_0 \beta \left( \frac{V_{00} \left( \frac{R_{02}}{R_{01} + R_{01}} - V_B \right)}{R_{01} + R_{02}} \right)$$
 and note  $V_B = 0.7 V_B$ 

choose 
$$R_{02}R_{01} - 1eTs$$
 say we mant a high input impedance  
 $R_{0} = \left(\frac{V_{00}}{2} - 0.45\right) \left[\frac{\beta}{R_{01}}\left(V_{00} - 0.7\left(\frac{R_{01}+R_{02}}{R_{02}}\right)\right)^{-1}\right]$ 

example: Voo = 10V,  $\beta = 100$ ,  $R_{B_1} = 9K$ ,  $R_{B_2} = 11k$  $L_{b} = (4.55) \left[\frac{100}{9000} (10 - 7)\right]^{-1} = 136.5 R$ 

5.83  

$$\frac{F_{OT} \beta = \infty \text{ and } R \text{ open}}{i_{B1} = i_{B2} = 0, a_1 = a_2 = 1$$

$$+ 9V \quad I_{D1} = 9 - 0.7 = 0.07mA$$

$$80K + 40K$$

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$$VB1 = 0.7 + 0.07m \times 40K$$

$$DI \qquad = 3.5V$$

$$40K \quad VE1 = VB1 - 0.7V$$

$$= 3.5 - 0.7 = 2.8V$$

$$IE1 = 2.8V = 1.4mA$$

$$IE1 = I_{C1} \text{ since } a = 1$$

$$Vc_1 = 9V - 2K \times 1.4m - 0.7 = 5.51$$

$$Vc_B = 2V \rightarrow Transistor is in$$

$$active mode.$$

$$VB2 = Vc_1 = 5.5V$$

$$VE2 = 5.5 + 0.7 = 6.2V$$

$$IE2 = 9 - 6.2 = 28mA$$

$$IE2 = I_{C2} \text{ since } a = 1$$

$$\Rightarrow Vc_2 = 28mA \times 10002 = 2.8V$$

$$\frac{For \beta = \infty \text{ and } R \text{ connected}:}{Still: VB1 = 3.5V}, VE1 = 2.8V$$

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Since the voltage across the top two resistors is equal: ICIX2K = IEZX 100 IEZ= 20ICI also: I cI=IEI / I CZ=IEZ 1 ICI 120 Ici +2.80. F Vcz 1.4mA, 2K = 2.84 Vc2 \$2.4K 100 2.4K ¥ 100 1.4m - Ic1 = 20 Ic1 - Vez 100 -> Vc2 = 100 × (21. Ic1 - 1.4m) 1 also: Vc2-2.8V = 1.4mA - Ici 2KA -> Vc2 = 5.6 - Ic1 × 2K (2) Solving for Ici from @ x2 ICI = 1.4mA Substituting in either Ov@ Vc2 = 2.8V and: VE2= 9-100×1.4m = 8.86V VBZ = VCI = 8.86-0.7 = 9.16V For B=100 and Kopen:

For 13=100 and Kopen: In the previous two cases IDI = 0.07mA, IEI = 1.4mA 14 B=100 → IBI = 0.014mA D which is a significant amount compared to 0.07m -7 must be taken into account

The bottom two resistors have equal valtage draps thus, CONT.

2K × IEI = 40K × IDI -> IDI = 0.05 × IEI 3 also: IDI + IBI = 9- VBI FROM B 80K  $IEI\left(\frac{1}{\beta+1}+0.05\right)$ for B = 100: 0.06 × IE1 = 9 - VBI 80K -> VBI = 9 - 4800 × IEI (4) also: VBI= 0.7 + IEIx2K (3) From @ 1 (5) { VBI = 3.11 // IEI = 1.22mA UEI= 1.22m ×2K→ VEI = 2.44V ICI = & IE = 0.99 × 1.22m = 1.2mA Again: voltage drop on top two resistors is equal 2K. ID2 = 100. IE2 ID2 = 0.05 IE2 but ID2 = 1.2m - IE2 13+1  $\implies 1.2 \text{ mA} = (0.05 + 1)^{-1}$ IE2 B+1 0.06 IEZ = 20mA VE2 = 9 - 100 x 20m = 7V VB2 = Va1 = 7-0.7 = 6.3V ICI = & IEI = 19.8mA Vez = 100×19.8mA = 1.98V For B=100 and R connected: To simplify the solution : assume ion R'is C< IEI -> VEI = 2.44V

R=2K iR \$ 16.3 IEI IEI J 2.44 ----\_\_\_\_\_ --- Vez 2KS 1.22MA 3100 From top of circuit: IE2 = Ici/0.06 Icz = K2 . IEI 0.06 Ic2 = 16.3 × IE1 To obtain IEI: 1,22m - IEI = 16.3IEI - Vez 100 Vc2 = 100 (17.2 IEI - 1.22m) @ also: Vez - 2.44 = 1.22m - IEI ZK → VC2 = 2.44 - 2000 IE1+2.44 = 4.88 - 2×103. IEI (7) From (7) 1(8); IE1= 1.34mA Vc2 = 2.18V Elus, Ic1 = 1, 33 mA IE2 = 22.1 mA VE2 = 9 - 22.1 mx 100 = 6.79V VB2 = 6.78-0.7 = 6.09V To confirm initial assumption on lof R: 2.44-2.18 = 0.13 mA 2K which is 10 times smaller than IEI

2#3

Vc = VB is The condition

$$-0.7 - R_{Y} I_{(1)} \ge -R_{0} I_{B_{1}}$$
and use  $I_{B_{1}} = \frac{F_{c_{1}}}{p}$  and  $I_{c_{1}} = dI_{C_{1}} = \frac{\beta}{\beta\tau_{1}} I_{C_{1}}$ 

$$-0.7 - 50 \left(\frac{\beta}{\beta\tau_{1}}\right) I_{MA} \ge -70k \left(\frac{I_{MA}}{\beta\tau_{1}}\right)$$

$$-\left(\beta\tau_{1}\right) 0.7 - (50m)\beta \ge -70$$

$$\beta \le 92.4$$

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